imall

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1A, 50V - 600V Glass Passivated Super Fast Rectifiers

FEATURES

- High efficiency, low VF
- High current capability
- High reliability
- Low power loss
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

MECHANICAL DATA

Case: DO-204AL (DO-41)

Molding compound, UL flammability classification rating 94V-0 Part no. with suffix "H" means AEC-Q101 qualified Packing code with suffix "G" means green compound (halogen-free) **Terminal:** Pure tin plated leads, solderable per JESD22-B102 Meet JESD 201 class 2 whisker test **Weight:** 0.35 g (approximately)







DO-204AL (DO-41)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS (T _A =25°C unless otherwise noted)										
	SYMBOL	SF	SF SF SF SF SF SF SF				SF	SF		
PARAMETER		11G	12G	13G	14G	15G	16G	17G	18G	UNIT
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	150	200	300	400	500	600	V
Maximum RMS voltage	V _{RMS}	35	70	105	140	210	280	350	420	V
Maximum DC blocking voltage	V _{DC}	50	100	150	200	300	400	500	600	V
Maximum average forward rectified current	I _{F(AV)}					1				Α
Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}			30				А		
Maximum instantaneous forward voltage (Note 1) @ 1 A	V _F		0.	95	1.3 1.7			.7	V	
Maximum reverse current @ rated V_R T _J =25°C T _J =125°C	I _R	5 100				μA				
Maximum reverse recovery time (Note 2)	t _{rr}	35					ns			
Typical junction capacitance (Note 3)	CJ	20 10				pF				
Typical thermal resistance	R _{θJL} R _{θJA}	20 80			°C/W					
Operating junction temperature range	TJ	- 55 to +150							°C	
Storage temperature range	T _{STG}	- 55 to +150						°C		

Note 1: Pulse Test with PW=300µs, 1% Duty Cycle

Note 2: Reverse Recovery Test Conditions: I_F =0.5A, I_R =1.0A, I_{RR} =0.25A

Note 3: Measured at 1 MHz and Applied Reverse Voltage of 4.0V D.C.



SF11G - SF18G

Taiwan Semiconductor

ORDERING INFORMATION

PART NO.	PART NO. SUFFIX	PACKING CODE	PACKING CODE SUFFIX ^(*)	PACKAGE	PACKING		
SF1xG (Note 1)		A0	G	DO-41	3,000 / Ammo box (52mm taping)		
	Ц	R0		DO-41	5,000 / 13" Paper reel		
	Н	R1		DO-41	5,000 / 13" Paper reel (Reverse)		
		B0		DO-41	1,000 / Bulk packing		

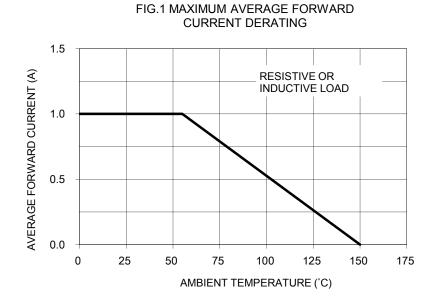
Note 1: "x" defines voltage from 50V (SF11G) to 600V (SF18G)

*: Optional available

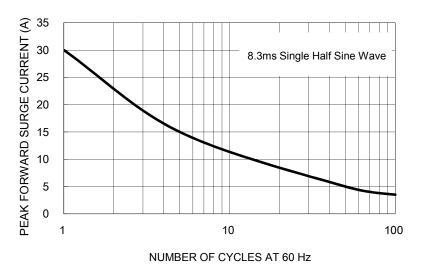
EXAMPLE										
PREFERRED P/N	PART NO.	PART NO. SUFFIX	PACKING CODE	PACKING CODE SUFFIX	DESCRIPTION					
SF18GHA0G	SF18G	Н	AO	G	AEC-Q101 qualified Green compound					

RATINGS AND CHARACTERISTICS CURVES

 $(T_A=25^{\circ}C \text{ unless otherwise noted})$







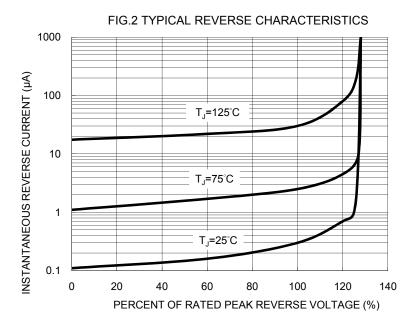
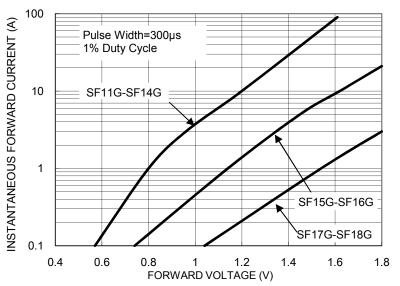


FIG. 4 TYPICAL FORWARD CHARACTERISTICS





Taiwan Semiconductor

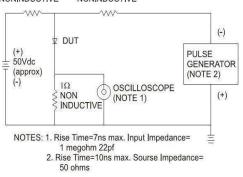
70 f=1.0MHz 60 JUNCTION CAPACITANCE (pF) Vsig=50mVp-p 50 40 30 SF11G-SF14G 20 10 SF15G-SF18G 0 0.1 1 10 100 1000 REVERSE VOLTAGE (V)

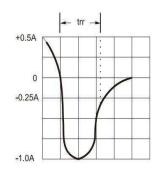
FIG. 5 TYPICAL JUNCTION CAPACITANCE

FIG.6 REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

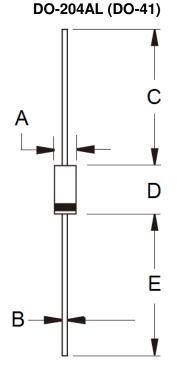
Unit (inch)

50Ω NONINDUCTIVE 10Ω NONINDUCTIVE









DIM. Min Max Min Мах 2.00 2.70 0.079 0.106 А В 0.71 0.86 0.028 0.034 25.40 1.000 С --D 4.20 0.165 5.20 0.205 Е 25.40 -1.000 _

Unit (mm)

MARKING DIAGRAM



- P/N = Specific Device Code G = Green Compound YWW = Date Code
- F = Factory Code



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